

MUR520D THRU MUR560D

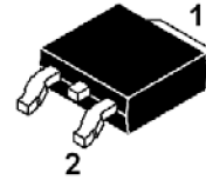
Super Fast Rectifiers

Reverse Voltage - 200 to 600 V

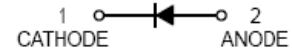
Forward Current – 5 A

Features

- Low leakage
- Low forward voltage
- High current capability
- The plastic material carries U/L recognition 94V-0



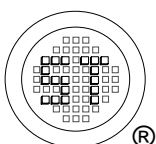
TO-252



Maximum Ratings and Electrical Characteristics

Ratings at 25 °C operating temperature range applies unless otherwise specified.

Parameter	Symbols	MUR520D	MUR540D	MUR560D	Units
Recurrent Peak Reverse Voltage	V_{RRM}	200	400	600	V
RMS Voltage	V_{RMS}	140	280	420	V
DC Blocking Voltage	V_{DC}	200	400	600	V
Average Forward Rectified Current at $T_A = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	5			A
Peak Forward Surge Current 8.3 ms Single Half-sine-wave Superimposed on Rated Load	I_{FSM}	60			A
Forward Voltage at $I_F = 5\text{ A}$	V_F	0.975	1.3	1.5	V
Reverse Current at Rated DC Blocking Voltage	I_R	5 250	10 500		μA
Reverse Recovery Time at $I_F = 0.5\text{ A}$, $I_{rr} = 0.25\text{ A}$, $I_R = 1\text{ A}$	t_{rr}	25	50		ns
Operating Junction Temperature Range	T_j	150			$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150			$^\circ\text{C}$

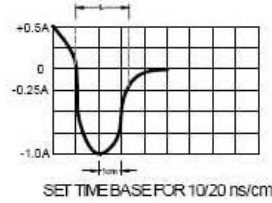
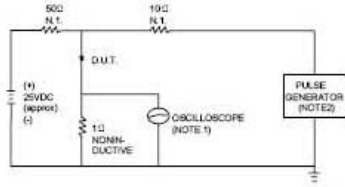


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FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ, 22pF.
2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

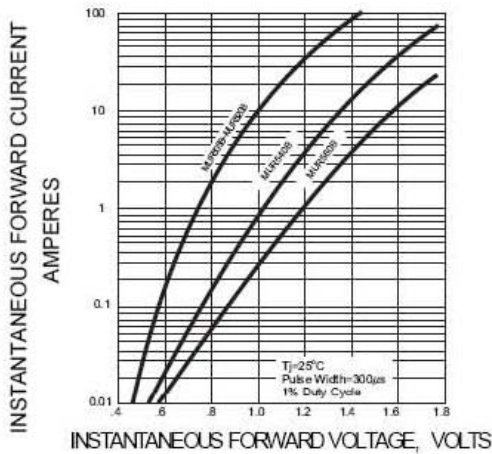


FIG.3 -- PEAK FORWARD SURGE CURRENT

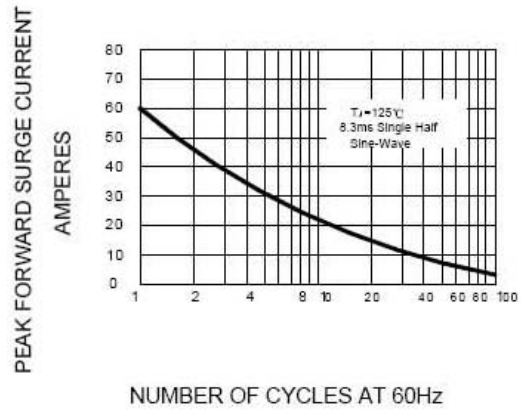
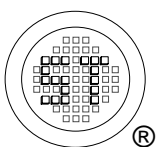
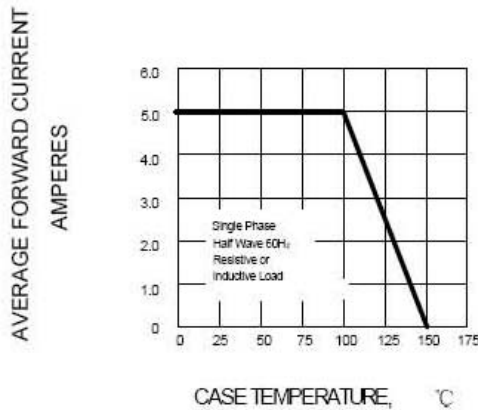


FIG.4 FORWARD DERATING CURVE

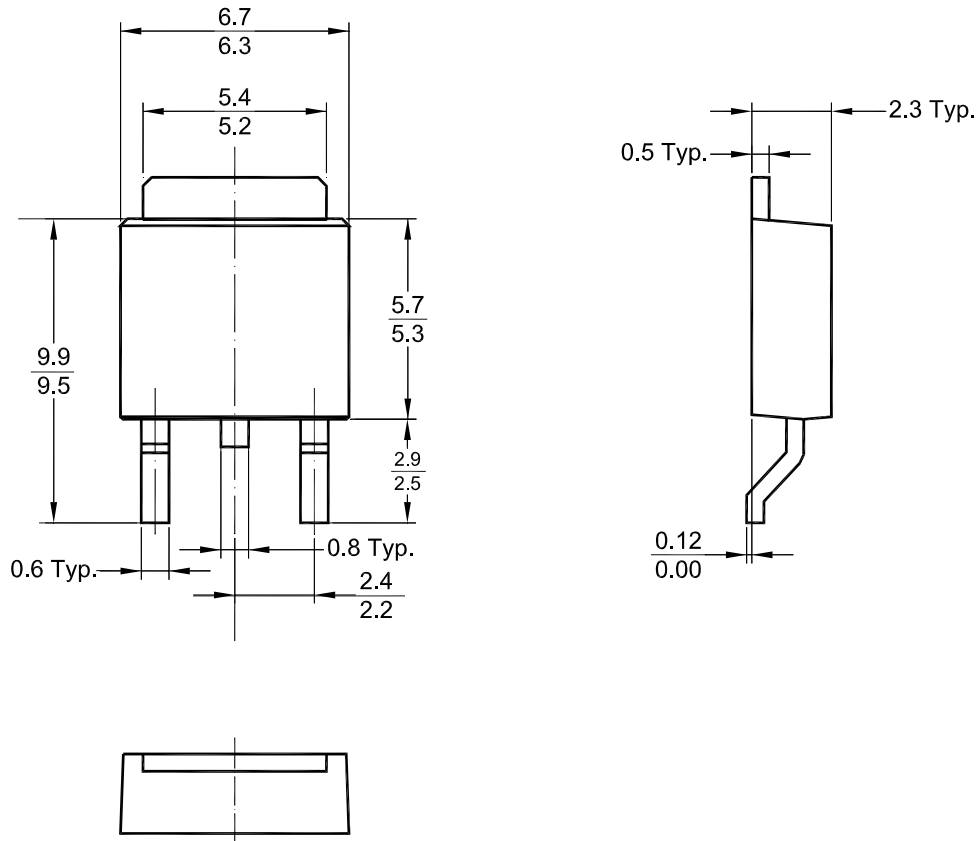


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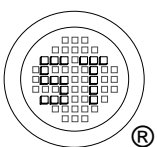


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TO-252 PACKAGE OUTLINE



Dimensions in mm



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